NSN 5962-01-165-3120

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-165-3120

Body Length:

1.290 inches

Body Width:

0.600 inches

Body Height:

0.180 inches

Maximum Power Dissipation Rating:

53.0 milliwatts

Operating Tempurature Range:

-25.0/+85.0 degrees celsius

Storage Tempurature Range:

-65.0/+125.0 degrees celsius

End Application:

5865-01-096-4994 radar simulator

Features Provided:

Programmable and electrostatic sensitive and ultraviolet erasable and 3-state output

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Input Circuit Pattern:

14 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

6.0 volts power source

Time Rating Per Chacteristic:

450.00 nanoseconds propagation delay time, low to high level output

Memory Device Type:

Rom

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0